RENESAS

3.3V CMOS ONE-TO-FOUR ADDRESS/CLOCK DRIVER WITH 3-STATE OUTPUTS AND 5 VOLT TOLERANT I/O

IDT74LVC16344A OBSOLETE PART

FEATURES:

- Typical tsk(o) (Output Skew) < 250ps
- ESD > 2000V per MIL-STD-883, Method 3015; > 200V using machine model (C = 200pF, R = 0)
- Vcc = 3.3V ± 0.3V, Normal Range
- Vcc = 2.7V to 3.6V, Extended Range
- CMOS power levels (0.4µ W typ. static)
- · All inputs, outputs, and I/O are 5V tolerant
- · Supports hot insertion
- Available in SSOP and TSSOP packages

DRIVE FEATURES:

- · High Output Drivers: ±24mA
- · Reduced system switching noise

APPLICATIONS:

- 5V and 3.3V mixed voltage systems
- Data communication and telecommunication system

DESCRIPTION: The LVC16344A is a 1:4 address/clock driver built using advanced dual

metal CMOS technology. This high speed, low power device provides the ability to fanout to memory arrays. Eight banks, each with a fanout of 4, and 3-state control provide efficient address distribution. One or more banks may be used for clock distribution.

All pins of this address line driver can be driven from an r 3.3V or 5V devices. This feature allows the use of this device as a transmission a mixed 3.3V/5V supply system

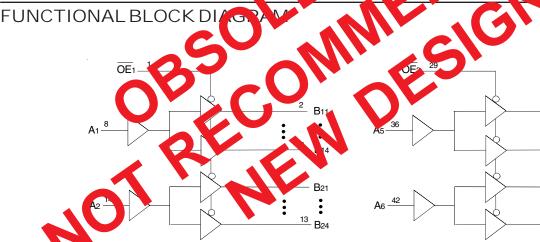
The LVC16344, the theen designed with a ± 2 tmAr utput driver. This driver is captule of viving a moderate to eavy load while maintaining

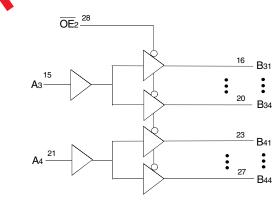
34 — B51

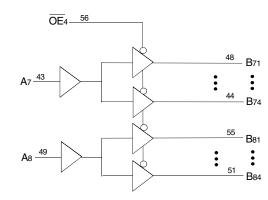
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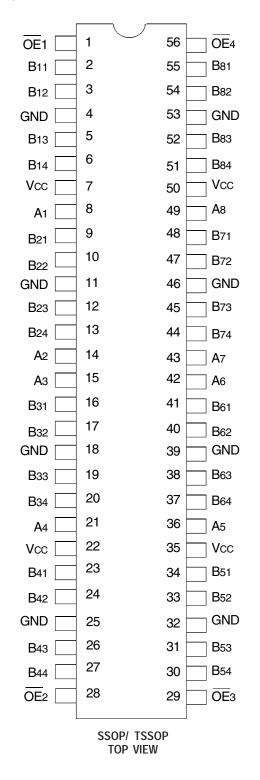


INDUSTRIAL TEMPERATURE RANGE

JANUARY 2004

IDT74LVC16344A 3.3VCMOSONE-TO-FOUR ADDRESS/CLOCK DRIVER

PINCONFIGURATION



INDUSTRIALTEMPERATURERANGE

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Description	Max	Unit
VTERM	Terminal Voltage with Respect to GND	–0.5 to +6.5	V
Tstg	Storage Temperature	-65 to +150	°C
Ιουτ	DC Output Current	-50 to +50	mA
Іік Іок	Continuous Clamp Current, VI < 0 or Vo < 0	-50	mA
lcc Iss	Continuous Current through each Vcc or GND	±100	mA

NOTE:

 Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

CAPACITANCE (TA = +25°C, F = 1.0MHz)

Symbol	Parameter ⁽¹⁾	Conditions	Тур.	Max.	Unit
CIN	Input Capacitance	VIN = 0V	4.5	6	pF
Соит	Output Capacitance	Vout = 0V	6.5	8	pF
Ci/o	I/O Port Capacitance	VIN = 0V	6.5	8	pF

NOTE:

1. As applicable to the device type.

PINDESCRIPTION

Pin Names	Description	
ŌĒx	3-State Output Enable Inputs (Active LOW)	
Ax	Ax Data Inputs	
Вхх	3-State Outputs	

FUNCTION TABLE⁽¹⁾

Inp	Outputs	
ŌĒx	Ах	Вхх
L	L	L
L	Н	Н
Н	Х	Z

NOTES:

1. H = HIGH Voltage Level

X = Don't Care

L = LOW Voltage Level

Z = High-Impedance

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DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Operating Condition: $TA = -40^{\circ}C$ to $+85^{\circ}C$

Symbol	Parameter	Те	st Conditions	Min.	Тур. ⁽¹⁾	Max.	Unit
Vih	Input HIGH Voltage Level	Vcc = 2.3V to 2.7V		1.7	_	_	V
		Vcc = 2.7V to 3.6V		2	_	_	
Vil	Input LOW Voltage Level	Vcc = 2.3V to 2.7V		_	_	0.7	V
		Vcc = 2.7V to 3.6V		_	-	0.8	
liн lil	Input Leakage Current	Vcc = 3.6V	VI = 0 to 5.5V	-	-	±5	μA
lozн lozl	High Impedance Output Current (3-State Output pins)	Vcc = 3.6V	Vo = 0 to 5.5V	-	-	±10	μA
loff	Input/Output Power Off Leakage	VCC = 0V, VIN or VO ≤ 5	.5V	-	-	±50	μA
Vik	Clamp Diode Voltage	Vcc = 2.3V, IIN = -18mA	l.	_	-0.7	-1.2	V
Vн	Input Hysteresis	Vcc = 3.3V		_	100	_	mV
ICCL ICCH	Quiescent Power Supply Current	Vcc = 3.6V	VIN = GND or Vcc	-	-	10	μA
lccz			$3.6 \le VIN \le 5.5V^{(2)}$	—	—	10	
∆lcc	Quiescent Power Supply Current Variation	One input at Vcc - 0.6V,	One input at Vcc - 0.6V, other inputs at Vcc or GND		-	500	μA

NOTES:

1. Typical values are at Vcc = 3.3V, +25°C ambient.

2. This applies in the disabled state only.

OUTPUT DRIVE CHARACTERISTICS

Symbol	Parameter	Test Conditions ⁽¹⁾		Min.	Max.	Unit
Vон	Output HIGH Voltage	Vcc = 2.3V to 3.6V	Iон = - 0.1mA	Vcc-0.2	—	V
		Vcc = 2.3V	Iон = – 6mA	2	_	
		Vcc = 2.3V	Iон = – 12mA	1.7	_	
		Vcc = 2.7V		2.2	_	
		Vcc = 3V		2.4	_	
		VCC = 3V	Iон = - 24mA	2.2	—	
Vol	Output LOW Voltage	Vcc = 2.3V to 3.6V	IoL = 0.1mA	—	0.2	V
		Vcc = 2.3V	Iol = 6mA	—	0.4	
			IoL = 12mA	_	0.7	
		Vcc = 2.7V	Iol = 12mA	_	0.4	
		Vcc = 3V	IOL = 24mA	_	0.55	

NOTE:

1. VIH and VIL must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate Vcc range. TA = -40° C to $+85^{\circ}$ C.



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INDUSTRIAL TEMPERATURE RANGE

OPERATING CHARACTERISTICS, Vcc = 3.3V ± 0.3V, TA = 25°C

Symbol	Parameter	Test Conditions	Typical	Unit
Cpd	Power Dissipation Capacitance per Buffer/Driver Outputs enabled	CL = 0pF, f = 10Mhz		pF
Cpd	Power Dissipation Capacitance per Buffer/Driver Outputs disabled			

SWITCHING CHARACTERISTICS⁽¹⁾

		Vcc =	= 2.7V	Vcc = 3.3	V ± 0.3V	
Symbol	Parameter	Min.	Max.	Min.	Max.	Unit
tPLH	Propagation Delay			1.5	4.4	ns
t PHL	Ax to Bxx					
tpzh	Output Enable Time			1.5	5.8	ns
tPZL	OEx to Bxx					
tphz	Output Disable Time			1.5	5.2	ns
tPLZ	OEx to Bxx					
tsk(b)	Skew between outputs of same bank and same package			-	350	ps
	(same transition)					
tsk(o)	Skew between outputs of all banks and same package			-	500	ps
	(A1 through A8 tied together) ⁽²⁾					

NOTES:

1. See TEST CIRCUITS AND WAVEFORMS. TA = -40° C to $+85^{\circ}$ C.

 $2. \ \ \, \text{Skew between any two outputs of the same package and switching in the same direction.}$

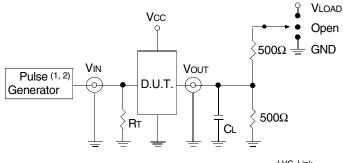
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TEST CIRCUITS AND WAVEFORMS

TESTCONDITIONS

Symbol	Vcc ⁽¹⁾ =3.3V±0.3V	Vcc ⁽¹⁾ =2.7V	Vcc ⁽²⁾ =2.5V±0.2V	Unit
Vload	6	6	2 x Vcc	V
Vih	2.7	2.7	Vcc	V
Vτ	1.5	1.5	Vcc / 2	V
Vlz	300	300	150	mV
Vhz	300	300	150	mV
Cl	50	50	30	рF



LVC Link

Test Circuit for All Outputs

DEFINITIONS:

CL = Load capacitance: includes jig and probe capacitance.

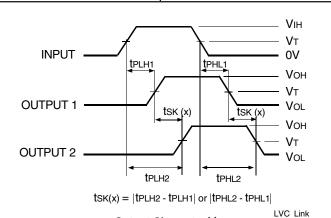
 $\mathsf{R} \mathsf{T}$ = Termination resistance: should be equal to $\mathsf{Z} \mathsf{O} \mathsf{U} \mathsf{T}$ of the Pulse Generator.

NOTES:

1. Pulse Generator for All Pulses: Rate \leq 10MHz; tF \leq 2.5ns; tR \leq 2.5ns. 2. Pulse Generator for All Pulses: Rate \leq 10MHz; tF \leq 2ns; tR \leq 2ns.

SWITCH POSITION

Test	Switch
Open Drain Disable Low Enable Low	Vload
Disable High Enable High	GND
All Other Tests	Open



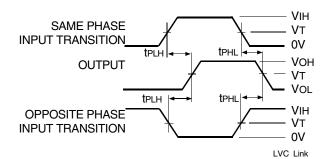
Output Skew - tsκ(x)

NOTES:

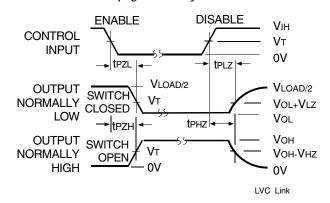
1. For tsk(o) OUTPUT1 and OUTPUT2 are any two outputs.

2. For tsk(b) OUTPUT1 and OUTPUT2 are in the same bank.





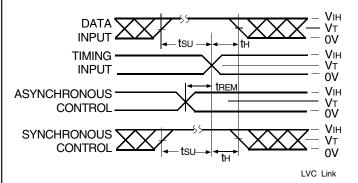
Propagation Delay

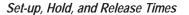


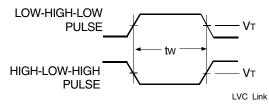
Enable and Disable Times

NOTE:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.





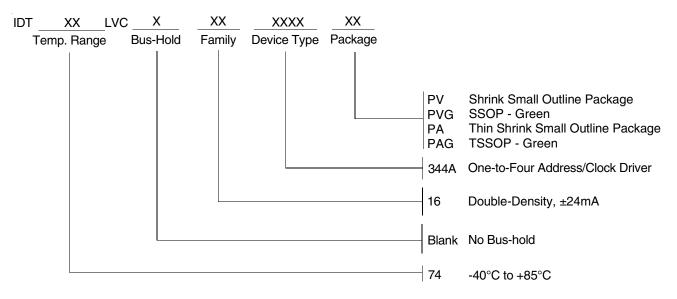


Pulse Width



IDT74LVC16344A 3.3V CMOS ONE-TO-FOUR ADDRESS/CLOCK DRIVER

ORDERING INFORMATION



DATASHEET DOCUMENT HISTORY

07/28/2003PDN# L-03-04 issued. See IDT.com for PDN specifics.09/03/2019Datasheet changed to Obsolete Status.

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